Comparison of the plasma temperature and electron number density of pulsed electrolyte cathode atmospheric pressure discharge and direct current solution cathode glow discharge

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Abstract: A novel plasma source of pulsed electrolyte cathode atmospheric pressure discharge (pulsed-ECAD) driven by an alternating current (AC) power supply coupled with a high voltage diode was generated, and the discharge was generated in the open-to-air atmosphere between a metal electrode and a small-sized flowing liquid cathode. The spatial distribution of plasma temperatures (excitation, vibrational and rotational) of the pulsed-ECAD were investigated. The electron excitation temperature of H $T_{exc}(H)$, vibrational temperature of N$_2$ $T_{vib}(N_2)$, and rotational temperature of OH $T_{rot}(OH)$ were measured as 4900±36-6800±108 K, 4600±86-5800±100 K and 1050±20-1140±10 K, respectively. Meanwhile, the temperature characteristics of dc solution cathode glow discharge (dc-SCGD) were also studied for comparison with pulsed-ECAD. The effects of operating parameters, including discharge voltage and discharge frequency, on the plasma temperatures were investigated. The electron number density determined in the discharge system and dc-SCGD were within the range (3.8–18.9) $\times 10^{14}$ cm$^{-3}$ and 2.6$\times 10^{14}$-17.2$\times 10^{14}$ cm$^{-3}$, respectively.

Keywords: pulsed electrolyte cathode atmospheric pressure discharge (pulsed-ECAD); plasma temperatures; temperature characteristics; electron number density

1. Introduction

Glow discharge generated with solution-electrodes, a type of atmospheric pressure glow discharge where one or both electrodes is a flowing liquid, has enjoyed increasing interest over recent years, because of its potential application in analytical atomic spectroscopy [1,2]. The first solution electrode system used for analytical atomic spectroscopy was developed in 1993 by Cserfalvi et al., who later named source an electrolyte cathode atmospheric pressure glow discharge (ELCAD)[3]. Since then multiple sources based on a liquid electrode have been investigated, including the liquid sampling-atmospheric pressure glow discharge (LS-APGD) [4,5], liquid electrode plasma-Atomic emission spectrometry (LEP-AES) [6], liquid-film dielectric barrier discharge (LFDBD)[7] and liquid electrode spectral emission chip[8-11]. In 2005, a simple configuration of ELCAD was described by Webb et al. and given the name solution cathode glow discharge (SCGD), and this showed better analytical performance than the previous system [12]. The SCGD or other ELCAD-like sources offered important advantages over conventional plasma sources for solution analysis, such as inductively
coupled plasma-mass spectrometry (ICP-MS) [13] and inductively coupled plasma-atomic emission spectrometry (ICP-AES) [14]. Several reviews [15-20] detailed the development of all these discharges. The SCGD source was both inexpensive and simple, requiring no compressed gases or sample-solution nebulizer. It operated at lower power (~70 W), and exhibited lower spectral interference [21]. In order to evaluate the analytical performance of these excitation sources, their plasma parameters, including the electron excitation temperature, vibrational temperature, rotational temperature and electron number density, were investigated. The spatial distribution of the rotational temperature of OH (4000-8000 K) and the excitation temperature of Cu (5500-7500 K) were reported by Cservalvi et al. in an electrolyte cathode-atmospheric pressure discharge (ELCAD) source [22]. The excitation temperature of Fe and rotational temperature of OH as well as the emission intensities of the main species were investigated by Webb et al. [23,24] as a function of distance from the liquid cathode. Maximum temperatures and emission intensities were observed near the cathode region. Bruggeman et al.[25,26] reported the rotational temperatures and emission intensities observed near the cathode region. Bruggeman et al.[25,26] reported the rotational temperatures and emission intensities observed near the cathode region. Bruggeman et al.[25,26] reported the rotational temperatures and emission intensities observed near the cathode region. Bruggeman et al.[25,26] reported the rotational temperatures and emission intensities observed near the cathode region. Bruggeman et al. [29] and the results showed that the electron density and temperature varied from $2.4 \times 10^{14} \text{ cm}^{-3}$ and 1.8 eV in the center of the discharge to $0.8 \times 10^{14} \text{ cm}^{-3}$ and 1.5 eV near the outer edge of the plasma in the case of a metal anode. Li et al. [30] also measured the rotational temperature of OH in miniature flow Ar, He or N$_2$ dc discharges with a bulky liquid electrode. The rotational temperature of OH established for the He microjet was higher than the Ar microjet system.

Recently, a pulsed Electrolyte Cathode Atmospheric Pressure Discharge (pulsed-ECAD) was developed in our lab [31]. Unlike the dc-SCGD, the pulsed-ECAD was driven by an alternating current (AC) power supply coupled with a high voltage diode. The intensity of the emission spectral band of OH obtained in the pulsed-ELCD was far less than those in SCGD. The background signal intensities and SDs of the background signals were much lower than dc-SCGD’s. Clearly, there were still some differences in the chemistry and physics of the processes occurring in these sources. The knowledge gained from fundamental studies is helpful to explain the emission mechanisms and led to the potential to further improve analytical performance, as earlier studies had.

The aim of this work was the spectroscopic characterization of the pulsed electrolyte cathode plasma driven by an alternating-current power supply coupled with a high voltage diode. Various plasma parameters were measured in various experimental conditions. The parameters investigated included the electron excitation temperature $T_{\text{exc}}$(H), the vibrational temperature $T_{\text{vib}}$(N$_2$) and the rotational temperature $T_{\text{rot}}$(OH), as well as the electron number density $n_e$. These plasma parameters were measured and compared in the pulsed-ECAD and dc-SCGD systems. The possible plasma processes responsible for the excitation of the pulsed-ECAD are discussed here.

2. ECAD cell design

The experimental setup has been described previously [31] and is shown in Fig. 1. A glass capillary, which is a 25 µL micropipette (SAIHUA) with a 0.35 mm inner diameter and a 1.38 mm outer diameter, was used for the sampling inlet. An additional graphite tube with a diameter of 4 mm
was inserted axially by the glass capillary, 3 mm lower than the top of the glass capillary. The overflow from the capillary tip created an electrical connection between the solution exiting the micropipette and the graphite tube. The graphite tube and glass capillary were mounted in a PTFE waste reservoir mounted on a three-dimensional mobile platform in order to adjust the distance between the two electrodes. Sample solutions were introduced into the glass capillary by a peristaltic pump (BT-100, Jieheng, China), and overflowed continuously from the capillary tip, falling into the graphite tube. Positioned 1.6 mm above the capillary tip was a tungsten rod (φ2 mm × 7 mm, pinpoint sloped 45°) that served as the anode for the cell. To generate discharge plasma, an AC power supply (CTP-2000K, Suman Electronics Co., Ltd., Nanjing, China) was applied to the tungsten anode through a high voltage diode in order to cut the negative cycle high voltage. The frequency of the power supply could be changed from 4.7 kHz to 20 kHz, the maximum output power being 500 W. The ground of the power supply was connected to the additional graphite tube through a sample resistor of 51 Ω for the discharge current measurement. The applied discharge voltage and discharge frequency were measured using an oscilloscope (Tektronix, DPO 3054) connected to the high-voltage probe (Tektronix, P6015A).

The discharge plasma was imaged 1:1 with a quartz lens onto the optical fiber head. Two spectrometers were used in the experiments. A portable spectrometer (Ocean Optics Maya 2000 Pro) was employed to measure the emission spectrum of discharge and measure the electron excited temperature. The Maya 2000 Pro was a 182×110×47 mm spectrograph with a CCD detector. The 2048×64 pixel CCD (Hamamatsu S10420) was backthinned and binned vertically to enhance sensitivity. The configuration used in this study had a spectral range of 200-1100 nm, a 1200 line per mm grating, a 10 µm entrance slit and a spectral resolution of 1.00 nm FWHM. The experimental parameters for acquiring emission signals were 20 ms for the integration times and 10 measures in order to increase the stability and reduce the standard deviation of the spectral intensities. A computerized Czerny-Turner spectrometer (Andor SR-750A) was used to capture high resolution spectra for the vibrational temperature, rotational temperature and electron density calculation. The spectrometer was equipped with three ruled gratings: 2400 grooves/mm, 1200 grooves/mm and 300 grooves/mm, which could be changed under the control of the computer, to provide high and low resolution spectra in the wavelength range of 200–900 nm. A 2048×512 pixels intensified and gated CCD camera (Andor DH340T-18U-03) was attached to the output end of the spectrograph to detect the spectrally resolved lines. The ICCD camera was cooled to -15 °C by a Peltier cooler in order to reduce the noise.

![Fig. 1 Schematic diagram of the experimental setup](image)
3. Results and discussion

3.1 Electrical characteristics

Fig. 2 presents the waveforms of the discharge voltage and current of the pulsed-ECAD system when the discharge frequency is 4.7 kHz. As shown in Fig. 2, the cycle of the discharge is 214 µs. There is only one pulse in a cycle for both the discharge voltage and current. The duration time of the pulsed discharge voltage is about 0.8 µs, and the durations time of the pulsed discharge current is about 0.2 µs. Then the discharge voltage remains roughly unchanged and maintains about 950 V for about 100 µs, while the discharge current increases slowly to 180 mA over about 81.4 µs. Finally, the discharge voltage decreases to 390 V at the time 214 µs. The discharge current reduces to zero at 166 µs, and keeps this value until the end of the cycle.

![Voltage and current waveforms of the pulsed-ECAD between metal anode and solution cathode](image)

3.2 Electron Excitation Temperatures

The electron excitation temperature is one of the most important temperature parameters in the process of investigating the energy level distribution of the measured atom in the plasma source. It plays an important role in the excitation power of the plasma source. A two-line intensity ratio method was selected for the calculation of excitation temperature. When the thermal equilibrium or the local thermal equilibrium state is satisfied, the number of particles in the two energy states of an atom satisfies the Boltzmann distribution \([31]\). In our work, H\(_\alpha\) 656.3 nm and H\(_\beta\) 486.1 nm lines with excitation energies of 12.1 and 12.7 eV, respectively, were chosen for the determination of the excitation temperatures \(T_{exc}(H)\). As shown in Fig. 3, the spectral intensities of H\(_\alpha\) 656.3 nm and H\(_\beta\) 486.1 nm of pulsed-ECAD system were much lower than dc-SCGD discharge system.

![Emission spectra of (a) pulsed-ECAD and (b) dc-SCGD](image)

The spatial distribution of the electron excitation temperatures was determined using the two-line
intensity ratio method (Hα 656.3 nm and Hβ 486.1 nm lines). The electron excitation temperatures were obtained using the discharge systems of pulsed-ECAD and dc-SCGD with the optimal conditions (discharge voltage: 980 V, discharge frequency: 4.7 kHz, inter-electrode distance: 1.6 mm, flow rate: 1.75 mL min⁻¹ for pulsed-ECAD, inter-electrode distance: 3 mm, flow rate: 2.6 mL min⁻¹, discharge voltage: 1 kV for dc-SCGD). The same spectrometer (with the same parameters) and optical capture device were used. The results are presented in Fig. 3. As shown in Fig. 4, the electron excitation temperature of the pulsed-ECAD system (shown in Fig. 4 (a)) was higher near the anode and decreased with the increasing gap to the metal electrode. It is shown that the electron excitation temperature has an upward trend at the near cathode field. However, the electron excitation temperature at the near cathode region of dc-SCGD was weaker than other regions. This may be the reason that the optimal spectral emission positions of some elements (Li, Sr and Cd) were not located in the near cathode region [31]. Additionally, the electron excitation temperature near solution electrode was lower than other regions. This phenomenon was different from the electron excitation temperature obtained from the dc-SCGD system (shown in Fig. 4 (b)), which indicated that the electronic excitation ability of pulsed-ECAD at the water level was relatively weaker than that of dc-SCGD. The electron excitation temperatures of the pulsed-ECAD system and dc-SCGD system were in the range 4900±36–6800±108 K and 5700±5–19000±678 K, respectively. Compared to the work of Yoshinobu Kohara[33] whose discharge system (LEP-AES) was driven by a high-voltage DC pulse power, the excitation temperatures of the pulsed-ECAD system were relatively lower than for LEP-AES (8000 K). Additionally, the electron excitation temperature obtained by Peter Bruggeman [25] was 5750–7250 K, slightly higher than the pulsed-ECAD.

![Fig.4 The spatial distributions of the excitation temperatures of the pulsed-ECAD system and dc-SCGD system](image)

3.3 Vibrational Temperatures

The vibrational temperature is an important parameter of the plasma. It is related to the activity of the plasma and can reflect the energy exchange information of high energy particles and electrons in the plasma. The vibrational temperature determined from N₂ bands is calculated by the Boltzmann plot method, using the four bands of the C^3Π_u→B^3Π_g system, i.e., (0–2); (1–3); (2–4); (3–5) [8].

The Boltzmann slope method using the emission band of 380.4 nm (0-2) was shown in Fig. 5, and the fitting degree reached to 0.9909. In our work, the emission band of N₂(C^3Π_u→B^3Π_g) (0-2) was selected for the calculation of the vibrational temperature (shown in Fig. 6).
Under the optimal experimental conditions [30], the vibrational temperature of the pulsed-ECAD and dc-SCGD systems were obtained in the range 4600±86~5800±100K and 5150±200~13000±400K, respectively. The vibrational temperature of pulsed-ECAD was slightly higher than the temperature obtained by Jamróz[8], which was 3800~4200 K. The spatial distribution of the vibrational temperature is presented in Fig. 7. It is obvious that the vibrational temperatures obtained from the two systems had similar spatial distributions. Both vibrational temperatures were high at the middle of the discharge plasmas, which may be because electrons excite gases to ionize and electrons and ions are bipolar diffusion, charged ions are prone to complex reactions. The greater the number of charged particles, the more intense the collisions in this region. As diatomic molecules, the band of N₂ is mainly caused by collisions. Therefore, the vibrational temperature of the two discharge systems is higher in the middle region of the plasma. However, the vibrational bands of N₂ at the near cathode field of both discharge systems were blurry. These behaviors indicate that the energy exchange between energetic particles and electrons presented in the discharge plasmas is more frequent at the middle of the plasmas than at the near cathode field.
Fig. 7 The spatial distribution of the vibrational temperatures of pulsed-ECAD system and dc-SCGD system

3.4 Rotational Temperatures

The rotational temperature is also one of the most important parameters for the plasma. The method to calculate the rotational temperatures was described by Jamróz [8]. For the calculation of the rotational temperature of OH ($T_{rot}(OH)$), the (0-0) band of the OH $A^2\Sigma^+ \rightarrow X^2\Pi$ system with the band head at 309.3 nm was selected and its emission spectra acquired in the range 307 to 310 nm (shown in Fig. 8). The Boltzmann slope method using the emission band of OH (0-0) was shown in Fig. 9, and the fitting degree of the linear fit reached to 0.9844.

Fig. 8 Emission band of OH ($A^2\Sigma^+ \rightarrow X^2\Pi$)(0-0) in the pulsed-ECAD system

Fig. 9 Fitting Boltzmann diagram slash using the emission band of OH $A^2\Sigma^+ \rightarrow X^2\Pi$ system (0-0)

The rotational temperatures of OH ($A^2\Sigma^+ \rightarrow X^2\Pi$)(0-0) of pulsed-ECAD and dc-SCGD were 1050±20-1140±10 K and 2400±60-3050±50 K, respectively. It was shown that the rotational
temperatures of the pulsed-ECAD and dc-SCGD had the same variation tendency with the increasing of the gap to the metal electrode. The rotational temperature decreased with the increasing of the gap to the metal electrode and had the highest temperature near the anode. A similar rotational temperature was observed by Naoki et al. [29] in pulsed discharge system, and the rotational temperatures of OH were 1200-1600K. However, the rotational temperature of the discharge system investigated by Peter Bruggeman et al. [26] was in the range 3200-3750 K and the SCGD discharge system investigated by Michael Webb [23] was in the range 2800-3300K. There was three times higher than pulsed-ECAD. Additionally, the rotational temperature of OH of the discharge system studied by Piotr Jamróz[8] was in the range 3800-4200 K, which was nearly four times higher than the temperature presented here. The behavior of low rotational temperature of pulsed-ECAD indicated that the thermal effect produced by plasma was lower and the evaporation effect of plasma on the solution was relatively weak. The less aerosol generated around the discharge plasmas also indicates the behavior. Most of the metal ions in the solution may be injected into the plasma due to the cathode sputtering effect. The elements which can be detected by pulsed-ECAD system are alkali metal and alkaline earth metal elements with low demands for excitation energy. For most heavy metals, the excitation energy is too high, and the energy of cathode sputtering is not enough to excite them.

![Graph](image)

**Fig. 10** The spatial distributions of the rotational temperatures of the pulsed-ECAD system and the dc-SCGD system

### 3.5 Electron number density

The electron number density plays an important role in understanding the plasma generation processes (excitation, ionization, etc.) [8]. Stark broadening ($\lambda_S$ in nm) of the H$_\alpha$ 486.06 nm line was chosen for the determination of electron number densities ($n_e$ in cm$^{-3}$) because it provides reasonable accuracy and precision with a relatively simple experimental setup and does not perturb the plasma or require an assumption of thermodynamic equilibrium[23]. To take the values of $\lambda_S$, experimental profiles of the H$_\alpha$ line, averaged for five consecutive measurements, were fitted to a Lorentz function using an Origin program (shown in Fig. 11). The Lorentzian part of full widths at half maximum (FWHMs) of the resulting line profiles was corrected for the instrumental broadening and used in the formula ($\lambda_S / 4.800 = (n_e / 10^{17})^{0.68116}$[34].

The spatial distributions of electron number densities ($n_e$ in cm$^{-3}$) for the pulsed-ECAD and dc-SCGD systems were shown in Fig. 12. The electron number densities $n_e$ of the pulsed-ECAD system, were measured within the range $(3.8-18.9) \times 10^{19}$ cm$^{-3}$. Aleksandrov et al. [34] also measured the a the electron density in the high-voltage nanosecond discharge, and shown the electron density was
varied between $10^{14}$ and $10^{15}$ cm$^{-3}$, which was similar with our results. Compared to the results of Piotr Jamróz[8], which showed them in the range $(3.4-6.8)\times10^{14}$ cm$^{-3}$, the pulsed-ECAD system had higher electron number densities which indicated that the collision degree in the plasmas of pulsed-ECAD was more intense. The $n_e$ of pulsed-ECAD at the near cathode region was higher than $n_e$ at the near anode region by 5-6 times. However, the $n_e$ could not be measured when the distance between metal and solution electrodes was more than 1 mm. The same phenomenon was found in the dc-SCGD system. The electron number densities $n_e$ of dc-SCGD were determined to be in the range $2.6\times10^{14}$-$17.2\times10^{14}$ cm$^{-3}$. The electron number densities of the two discharge systems stepped up with increasing distance from the metal electrode. Additionally, the behavior of electron number densities near $8.5\times10^{14}$ cm$^{-3}$ for the negative glow and $2.5\times10^{14}$ cm$^{-3}$ for the positive column found by Michael R. Webb[23], was different from the space distribution of electron number densities of pulsed-ECAD, and its electron number densities relatively low.

The slightly higher electron number density in pulsed-ECAD than dc-SCGD plasma leads to the increase of electron collision frequency in pulsed-ECAD and the diminution of the electronic free path, which results in the diminution of electron energy obtained from the plasmas. Thus the excitation ability for heavy metal elements is weaker than dc-SCGD, and the reason maybe that only the spectra of the alkali metal and alkaline earth metal elements were occurred in the pulsed-ECAD system, because they need lower excitation power.

**Fig. 11** Lorenz fitting graph of H$\beta$ (486.06 nm)  

**Fig. 12** Spatial distribution of electron number densities ($n_e$ in cm$^{-3}$) of the pulsed-ECAD and dc-SCGD systems

### 3.6 Influence of experimental parameters on plasma temperatures

To better study the characteristics of the pulsed-ECAD plasmas, the dependences of the plasma
temperatures on the experimental parameters, including discharge voltage and discharge frequency, were investigated.

3.6.1 Effect of the discharge voltage

In this part, the influence of the discharge voltage (peak voltage) on the excitation temperature of H atoms, the vibrational temperature of N\(_2\) and the rotational temperature of OH were studied (shown in Fig. 13). With the increasing discharge voltage, the pressure on the particles in the discharge plasma becomes larger, and the greater the acceleration the particles obtain. The particles get faster, which makes the collisions more intense and results in an increased emission intensity of the spectra. Thus, the plasma temperatures become higher. When the discharge voltage was more than 980 V, the tungsten rod turns red and stray light was produced, which impacted the detection accuracy. A higher voltage also damaged the glass capillary tube and caused the discharge to become unstable [32].

![Fig. 13 Influence of discharge voltage on the plasma temperatures](image)

3.6.2 Influence of the discharge frequency

The effect of discharge frequency on the excitation temperature of H atoms, the vibrational temperature of N\(_2\), the rotational temperature of N\(_2\) and OH was also investigated by collecting the emission spectra of the pulsed-ECAD system with various discharge frequencies. The results were presented in Fig. 14. When the frequency was more than 5.7 kHz, stable plasma cannot be obtained. With increasing discharge frequency, the acceleration time of electrons and ions may be shorter. The cycles of discharge voltage and current were reduced and the voltage reaches its maximum quickly. Thus, the time worked on the electrons and ions was shortened in one cycle, which caused weaker collisions and results in a decrease of plasma temperature. The reason for the absence of investigation of discharge frequencies lower than 4.7 kHz is the limit of the power supply. Thus, it is possible that higher plasma temperatures could be obtained with a lower discharge frequency.
4. Conclusions

The temperature characteristics of the discharge plasmas of the source, sustained by an alternating current power supply coupled with a high voltage diode, were studied. The excitation temperature of H $T_{\text{exc}}$(H), the vibrational temperature of N$_2$ $T_{\text{vib}}$(N$_2$) and the rotational temperature of OH $T_{\text{rot}}$(OH) were measured to be 4900±36~6800±108 K, 4600±86~5800±100 K and 1050±20~1140±10 K, respectively. According to previous experimental results, plasma temperatures of the pulsed-ECAD system are lower than the dc-SCGD, which means the thermal desolvation effect is weak. The effects of experimental conditions, including discharge voltage and frequency, on plasma temperatures were also explored. Plasma temperatures increased with the discharge increasing, and decreased with discharge frequency increasing. Additionally, the electron number density, as derived from the Stark broadening of the H$_\beta$ line, was in the range $(3.8$–$18.9)\times10^{14}$ cm$^{-3}$. This was higher than the electron number density of the dc-SCGD system $(2.6\times10^{14}$–$17.2\times10^{14}$ cm$^{-3}$), but the temperature lower than the dc-SCGD system, and it means that the high-energy particles of pulsed-ECAD system is less than the dc-SCGD system.

Acknowledgements

This work was financially supported by Key Project of Foundation and Advanced Technology Research Project of Chongqing (cstc2015jcyjBX0016), Project of Entrepreneurship and Innovation for Returned Overseas Scholars of Chongqing(cx2017126) and Foundation and Advanced Technology Research Project of Chongqing (cstc2016jcyjA0389).

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